L Number	Hits	Search Text	DB	Time stamp
1	394060	((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:34
		memory)) EEPROM EPROM PROM E2PROM	US-PGPUB	
2	13787	(((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:34
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)		
3	10907	((((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:01
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)) and (control near3		
		gate)		
4	5754	(((((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:35
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)) and (control near3		
		gate)) and (eth\$3 pattern\$3)		
5	5755		USPAT;	2004/09/13 13:35
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)) and (control near3		
		gate)) and (eth\$3 pattern\$4)		
6	1371		USPAT;	2004/09/13 13:40
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	, , , , , , , , , , , , , , , , , , , ,
		(float\$3 near3 gate)) and (control near3		
		gate)) and (eth\$3 pattern\$4)) and (CMP		
		(chemical near3 mechanical near3 polish\$3))		
7	168516	((flash volatile (non-violatile) near5	EPO; JPO;	2004/09/13 13:34
		memory)) EEPROM EPROM PROM E2PROM	DERWENT;	
			IBM TDB	
8	8007	(((flash volatile (non-violatile) near5	EPO; JPO;	2004/09/13 13:34
		memory)) EEPROM EPROM PROM E2PROM) and	DERWENT;	
		(float\$3 near3 gate)	IBM TDB	
9	1063	((((flash volatile (non-violatile) near5	EPO; JPO;	2004/09/13 13:40
		memory)) EEPROM EPROM PROM E2PROM) and	DERWENT;	
		(float\$3 near3 gate)) and (eth\$3 pattern\$3)	IBM TDB	
10	6621	(((((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:35
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)) and (control near3		
		gate)) and (etch\$3 pattern\$4)		
12	1493	((((((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:36
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)) and (control near3		
		gate)) and (etch\$3 pattern\$4)) and (CMP		
		(chemical near3 mechanical near3 polish\$3))		
14	122	((((((flash volatile (non-violatile) near5	USPAT;	2004/09/13 13:37
		memory)) EEPROM EPROM PROM E2PROM) and	US-PGPUB	
		(float\$3 near3 gate)) and (control near3		
		gate)) and (etch\$3 pattern\$4)) and (CMP		
		(chemical near3 mechanical near3 polish\$3)))		
		not (((((((flash volatile (non-violatile)		
		near5 memory)) EEPROM EPROM PROM E2PROM) and		
		(float\$3 near3 gate)) and (control near3		
		gate)) and (eth\$3 pattern\$4)) and (CMP		
		(chemical near3 mechanical near3 polish\$3)))		
15	1896	((((flash volatile (non-violatile) near5	EPO; JPO;	2004/09/13 13:40
	i	memory)) EEPROM EPROM PROM E2PROM) and	DERWENT;	
	_	(float\$3 near3 gate)) and (etch\$3 pattern\$3)	IBM_TDB	
16	53	(((((flash volatile (non-violatile) near5	EPO; JPO;	2004/09/13 13:40
		memory)) EEPROM EPROM PROM E2PROM) and	DERWENT;	
		(float\$3 near3 gate)) and (etch\$3	IBM_TDB	
		pattern\$3)) and (CMP (chemical near3		
		mechanical near3 polish\$3))		